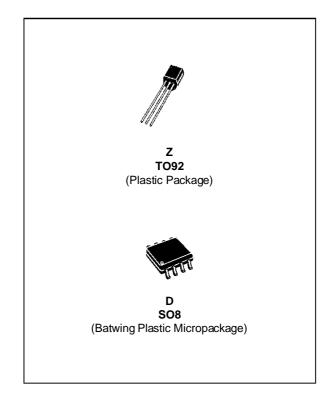


PROGRAMMABLE VOLTAGE REFERENCE

- ADJUSTABLE OUTPUT VOLTAGE : V_{ref} to 36V
- SINK CURRENT CAPABILITY: 1 to 100mA
 TYPICAL OUTPUT IMPEDANCE: 0.22W
- 1% AND 2% VOLTAGE PRECISION



DESCRIPTION

The TL431 is a programmable shunt voltage reference with guaranteed temperature stability over the entire temperature range of operation.

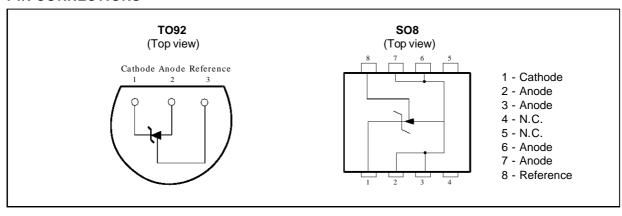
The output voltage may be set to any value between V_{ref} (approximately 2.5V) and 36V with two external resistors.

The TL431 operates with a wide current range from 1 to 100mA with a typical dynamic impedance of 0.22Ω .

ORDER CODES

Part number	Temperature Range	Pacl	kage
1 art number	remperature Kange	Z	D
TL431C/AC	0°C, +70°C	•	•
TL431I/AI	-40°C, +85°C	•	•

PIN CONNECTIONS



December 1995 1/6

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit	
V_{KA}	Cathode to Anode Voltage		37	V
lκ	Continuous Cathode Current Range		-100 to +150	mA
I _{ref}	Reference Input Current Range		-0.05 to +10	mA
T _{oper}	Operating Free-air Temperature Range	TL431C/AC TL431I/AI	0 to +70 -40 to +85	°C
T _{stg}	Storage Temperature Range		-65 to +150	°C

OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{KA}	Cathode to Anode Voltage	V _{ref} to 36	V
Iĸ	Cathode Current	1 to 100	mA

ELECTRICAL CHARACTERISTICS

T_{amb} = 25°C (unless otherwise specified)

Symbol	Parameter		TL431C			TL431AC		
Symbol	Farameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V _{ref}	$ \begin{array}{ll} \text{Reference Input Voltage - (figure 1)} \\ \text{V}_{\text{KA}} = \text{V}_{\text{ref}}, \text{ I}_{\text{K}} = 10 \text{mA} & \text{T}_{\text{amb}} = 25^{\text{o}}\text{C} \\ \text{T}_{\text{min.}} \leq \text{T}_{\text{amb}} \leq \text{T}_{\text{max.}} \\ \end{array} $	2.44 2.423	2.495	2.55 2.567	2.47 2.453	2.495	2.52 2.537	V
ΔV_{ref}	Reference Input Voltage Deviation Over Temperature Range - (figure 1, note1) $V_{KA} = V_{ref,\ l_K} = 10mA,\ T_{min.} \le T_{amb} \le T_{max.}$		3	17		3	15	mV
$\frac{\Delta V_{ref}}{\Delta V_{KA}}$	Ratio of Change in Reference Input Voltage to Change in Cathode to Anode Voltage - (figure 2) $I_{K} = 10 \text{mA} \qquad \qquad \Delta V_{KA} = 10 \text{V to } V_{ref} \\ \Delta V_{KA} = 36 \text{V to } 10 \text{V}$		-1.4 -1	-2.7 -2		-1.4 -1	-2.7 -2	mV/V
Iref	$ \begin{array}{l} \text{Reference Input Current - (figure 2)} \\ I_K = 10\text{mA}, \ R_1 = 10\text{k}\Omega, \ R_2 = \infty \\ \qquad \qquad$		1.8	4 5.2		1.8	4 5.2	μА
$\Delta I_{ m ref}$	Reference Input Current Deviation Over Temperature Range - (figure 2) $I_K = 10 \text{mA}, \ R_1 = 10 \text{k}\Omega, \ R_2 = \infty \\ T_{\text{min.}} \leq T_{\text{amb}} \leq T_{\text{max.}}$		0.4	1.2		0.4	1.2	μА
I _{min}			0.5	1		0.5	0.6	mA
l _{off}	Off-State Cathode Current - (figure 3)		2.6	1000		2.6	1000	nA
Z _{KA}	Dynamic Impedance - (figure 1, note 2) $V_{KA} = V_{ref}, \ \Delta I_K = 1 \ to \ 100mA, \ f \leq 1 kHz$		0.22	0.5		0.22	0.5	Ω

Notes: 1. ΔV_{ref} is defined as the difference between the maximum and minimum values obtained over the full temperature range.

V_{ref max.} - Vref min $V_{ref max.}$ $V_{ref min.}$ $V_{ref min.}$ $V_{ref min.}$ T1 T2 Temperatu

2. The dynamic Impedance is defined as $|Z_{\text{KA}}| = \frac{\Delta V_{\text{KA}}}{\Delta I_{K}}$

ELECTRICAL CHARACTERISTICS

 $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter		TL431I			TL431AI		
Syllibol	Faranteter	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
V _{ref}	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	2.44 2.41	2.495	2.55 2.58	2.47 2.44	2.495	2.52 2.55	V
ΔV_{ref}	Reference Input Voltage Deviation Over Temperature Range - (figure 1, note1) $V_{KA} = V_{ref}, I_{K} = 10 \text{mA}, T_{min.} \leq T_{amb} \leq T_{max.}$		7	30		7	17	mV
$\frac{\Delta V_{ref}}{\Delta V_{KA}}$	Ratio of Change in Reference Input Voltage to Change in Cathode to Anode Voltage - (figure 2) $I_K = 10 \text{mA} \qquad \qquad \Delta V_{KA} = 10 \text{V to } V_{\text{ref}} \\ \Delta V_{KA} = 36 \text{V to } 10 \text{V}$		-1.4 -1	-2.7 -2		-1.4 -1	-2.7 -2	mV/V
Iref	Reference Input Current - (figure 2) $I_{K} = 10\text{mA}, \ R_{1} = 10\text{k}\Omega, \ R_{2} = \infty \\ T_{amb} = 25^{\circ}\text{C} \\ T_{min.} \leq T_{amb} \leq T_{max}.$		1.8	4 6.5		1.8	4 6.5	μА
$\Delta I_{ m ref}$	Reference Input Current Deviation Over Temperature Range - (figure 2) $I_K = 10 \text{mA}, \ R_1 = 10 \text{k}\Omega, \ R_2 = \infty \\ T_{min.} \leq T_{amb} \leq T_{max}.$		0.8	2.5		0.8	1.2	μА
I _{min}			0.5	1		0.5	0.7	mA
I _{off}	Off-State Cathode Current - (figure 3)		2.6	1000		2.6	1000	nA
Z _{KA}	Dynamic Impedance - (figure 1, note 2) $V_{KA} = V_{ref}, \ \Delta I_K = 1 \ to \ 100 mA, \ f \le 1 kHz$		0.22	0.5		0.22	0.5	Ω

Notes : 1. ΔV_{ref} is defined as the difference between the maximum and minimum values obtained over the full temperature range.

range. $\Delta V_{ref} = V_{ref max.} - V_{ref min}$



2. The dynamic Impedance is defined as $|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_{K}}$

Figure 1: Test Circuit for $V_{KA} = V_{ref}$

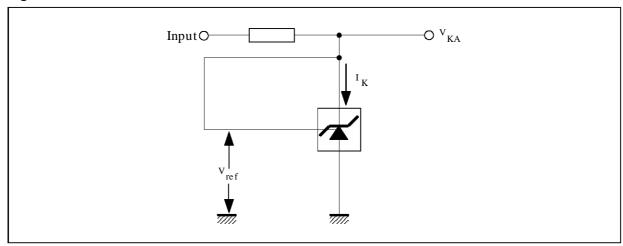


Figure 2 : Test Circuit for $V_{KA} > V_{ref}$

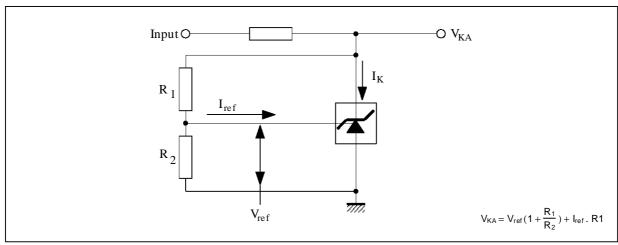
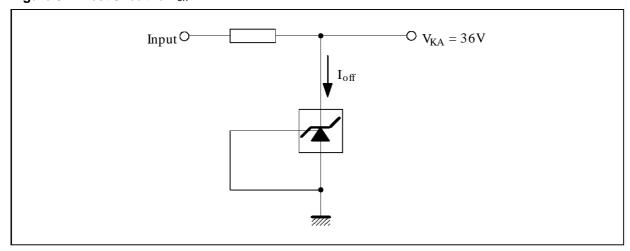
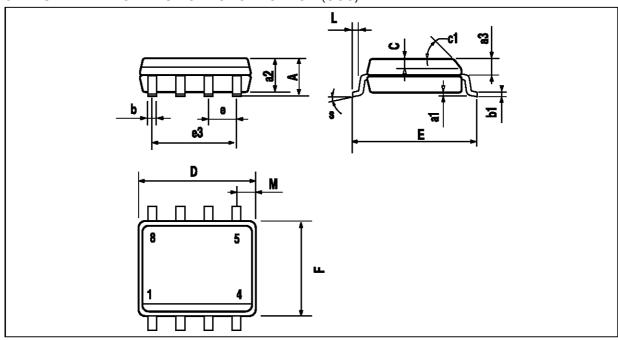


Figure 3: Test Circuit for Ioff



PACKAGE MECHANICAL DATA

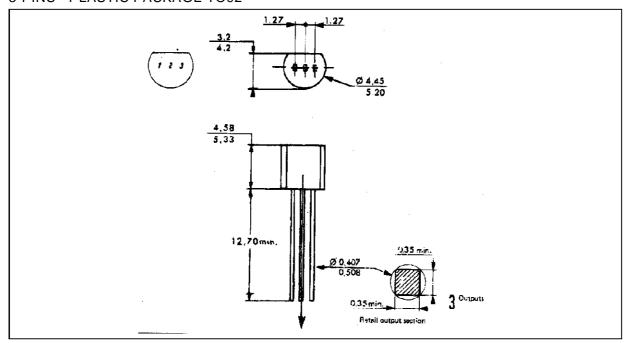
8 PINS - BATWING PLASTIC MICROPACKAGE (SO8)



Dimensions		Millimeters			Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.	
А			1.75			0.069	
a1	0.1		0.25	0.004		0.010	
a2			1.65			0.065	
a3	0.65		0.85	0.026		0.033	
b	0.35		0.48	0.014		0.019	
b1	0.19		0.25	0.007		0.010	
С	0.25		0.5	0.010		0.020	
c1			45°	(typ.)			
D	4.8		5.0	0.189		0.197	
Е	5.8		6.2	0.228		0.244	
е		1.27			0.050		
e3		3.81			0.150		
F	3.8		4.0	0.150		0.157	
L	0.4		1.27	0.016		0.050	
М			0.6			0.024	
S	8° (max.)						

PACKAGE MECHANICAL DATA

3 PINS - PLASTIC PACKAGE TO92



Dimensions		Millimeters			Inches	
Difficitsions	Min.	Тур.	Max.	Min.	Тур.	Max.
L		1.27			0.05	
В	3.2	3.7	4.2	0.126	0.1457	0.1654
01	4.45	5.00	5.2	0.1752	0.1969	0.2047
С	4.58	5.03	5.33	0.1803	0.198	0.2098
K	12.7			0.5		
O2	0.407	0.5	0.508	0.016	0.0197	0.02
а	0.35			0.0138		

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